A Density Functional Study of Zinc Oxide Elastic Properties Under High Pressure

Bin-Bin Wang and Ya-Pu Zhao

Abstract Zinc Oxide (ZnO) material has been widely used in piezoelectric devices, electro-optic devices, and biomedical sensors, etc. Among three crystal phases, ZnO with wurtzite structure (B4) is most common; thus it usually exists in natural ZnO materials. ZnO with zinc blend structure (B3) is another common crystal phase, which is metastable in nature. As observed by researchers, ZnO materials synthesized by chemical vapor deposition (CVD), which is one of the most popular methods to synthesize nanomaterials, have both B3 and B4 structures. In this paper, we discussed the elasticity and crystal structure of ZnO with the two structures under high pressure from 0 to 10 GPa. The CAmbridge Serial Total Energy Package (CASTEP) based on density functional theory (DFT) was used to perform the calculations. Both local density approximation (LDA) and generalized gradient approximation (GGA) were employed for comparison. We found that all the lattice constants decreased with the increasing pressure, and the relationship was linear, while the bulk moduli increased with the increasing environment pressure. However, the elastic constants (including C₁₁, C₁₂ and C₄₄ for B3; C₁₁, C₁₂, C₁₃, C₃₃ and C₄₄ for B4) showed a more sophisticated trend, which could be attributed to the particular symmetry of the crystal structure. The elastic constants denoting the elasticity of longitudinal directions would become larger with the increasing pressure, while the others show irregular trends. The results in this paper will be helpful in widening the application of devices based on ZnO nanomaterials.

Keywords ZnO • Elastic properties • Density functional theory (DFT) • Multi-scale simulation

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Abbreviations

CAPZ Ceperley-Alder –Perdew-Zunger

CASTEP CAmbridge Serial Total Energy Package

CVD Chemical Vapor Deposition
DFT Density Functional Theory
FEM Finite Element Method

GGA Generalized Gradient Approximation

HF Hartree-Fock

LDA Local Density Approximation

MD Molecular Dynamics
MM Molecular Mechanics
QM Quantum Mechanism

TBMD Tight Binding Molecular Dynamics

ZnO Zinc Oxide

1 Introduction

Zinc Oxide (ZnO), as the third generation semiconductor materials, has attracted much attention in the last decade. ZnO is a wide-band-gap semiconductor with a wide range of technological applications including electronic and electro-optic devices, catalysis, chemical sensors, and so on. Especially, ZnO film has been used as n-type conducting windows in thin film solar cells based on amorphous silicon. In recent years, many efforts have been made on the synthesis and applications of nanosized ZnO materials [1–4]. For example, we have investigated the junction structure of ZnO tetrapods, which would be helpful to understand the growth mechanism and applications of ZnO tetrapods [5]. ZnO occurs naturally as a mineral and its high pressure phase may be geologically important as a component of the lower mantle. ZnO usually crystallizes in three forms: hexagonal wurtzite (B4), cubic zincblende (B3) and the rarely observed cubic rocksalt (B1). The wurtzite structure is most stable under atmospheric condition and thus most common. The zinc blende form can be stabilized by growing ZnO on substrates with cubic lattice structure. In both cases, the zinc and oxide centers are tetrahedral. Besides, the rocksalt structure is only observed at relatively high pressures about 10 GPa.

The chemical vapor deposition (CVD) method is one of the simplest approaches, which has been widely used to produce ZnO nanostructures. Many studies reveal that the nanosized ZnO materials grown by CVD are wurtzite structured (B4), while the zinc blend (B3) structure exists relatively small in quantities [4, 6]. Furthermore, the elastic properties under high pressure should be studied extensively in order to expand the application of ZnO materials. The B4 structure is hexagonal, and there exists five independent elastic constants: C_{11} , C_{33} , C_{12} , C_{13} and C_{44} . Elastic constants C_{11} and C_{33} correspond to longitudinal modes along the [1000] and

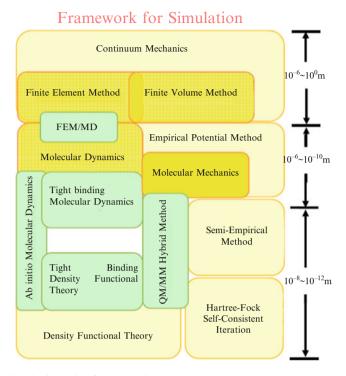


Fig. 1 Multi-scale simulation framework in the authors' group

[0001] directions, respectively. Elastic constants C_{44} and $C_{66} = (C_{11} - C_{12})/2$, owing to symmetry, can be determined from the sound velocity of transverse modes propagating along the [0001] and [1000] directions, respectively. The remaining constant C_{13} is present in combination with four other moduli in the velocity of modes propagating in less-symmetrical directions, such as [0011]. The B3 structure has higher symmetry than B_4 ; thus it has only three elastic constants denoted C_{11} , C_{12} and C_{44} .

The elastic properties of ZnO single crystals have been investigated by many researchers by both experimental and computational methods [7–12]. In this paper, we present the elastic constants and crystal constants of ZnO with B3 and B4 structures obtained by density functional theory (DFT), using both GGA and LDA approximations. Young's modulus and Poisson's ratio were also studied. Corresponding results would be helpful to widen the applications of ZnO materials in devices based on nanomaterials. Furthermore, the calculations were carried out on the simulation platform illustrated in Fig. 1, which had been constructed for multi-scale simulations, including DFT, quantum mechanics/molecular mechanics (QM/MM), tight binding molecular dynamics (TBMD), molecular dynamics (MD), and finite element method (FEM), etc. Results on multi-scale physical mechanics have attracted much attention in the corresponding field [13–15].

2 Model

The calculations were performed using the program CASTEP (CAmbridge Serial Total Energy Package), which uses DFT to provide a good atomic level description of all manner of materials and molecules. In our calculations, both LDA and GGA methods have been applied. The B3 and B4 structures are investigated in this paper, while B2 was not included because of its rareness. The crystal structures of both B3 and B4 are shown in Fig. 2.

CASTEP employs the DFT plane-wave pseudo potential method, which can perform first-principles quantum mechanics calculations that explore the properties of crystals and surfaces in materials such as semiconductors, ceramics, metals,

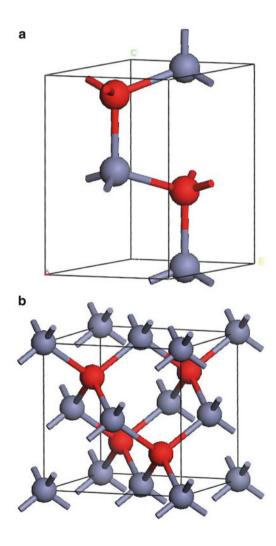


Fig. 2 Crystal structures of wurtzite and zinc blende ZnO: (a) wurtzite; (b) zinc blende

minerals, and zeolites. For LDA and GGA methods, the Ceperley-Alder–Perdew-Zunger local-density approximation (CAPZ) [16, 17] and Perdew-Wang generalized gradient approximation (PW91) [18] were employed to calculate ZnO's crystal properties. The environment pressure was applied as static hydrostatic pressure, and the values are 0, 2, 4, 6, 8, 10 GPa.

3 Results and Discussions

The crystal structures for the B3 and B4 phases of ZnO are presented in Fig. 2. The wurtzite ZnO belongs to the C_{6v4} (P_{63mc}) space group. The primitive cell includes two formula units, with all atoms occupying 2b sites of symmetry C_{3v} . The structure is described by two lattice constants a and c, and the internal parameter u, whereas the zinc blend structure is described by only one lattice constant a. Experimental results for lattice constant of B3 under atmospheic pressure is a = 4.58 Å, while a = 3.25 Å and c = 5.2 Å for B4.

Figure 3 shows the crystal constant of B3 ZnO decreases with increasing pressure, and the relationship is linear. Results with GGA are larger than the ones with LDA. Compared with experimental data, the actual value is between the results

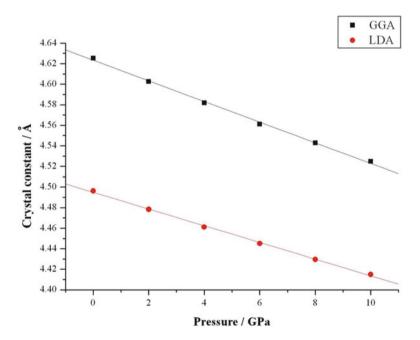


Fig. 3 Relationship between crystal constant and pressure for the B₃ structure

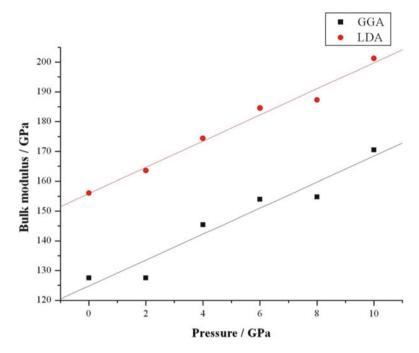
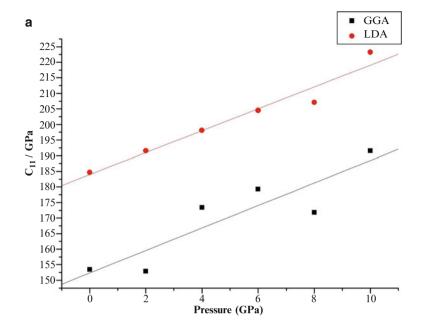


Fig. 4 Relationship between bulk modulus and pressure for the B₃ structure

obtained using GGA and LDA. The bulk modulus of B3 ZnO presented in Fig. 4 shows a similar situation; however the trend is opposite: bulk modulus increases with increasing pressure.

Different crystal structures have different numbers of elastic constants and higher symmetry would reduce the numbers. For ZnO crystals, B3 belongs to the cubic crystal system, while B4 belongs to the hexagonal crystal system. Thus B3 has three independent elastic constants (C_{11} , C_{12} and C_{44} , $C_{11} = C_{22} = C_{33}$; $C_{12} = C_{23} = C_{31}$; $C_{44} = C_{55} = C_{66}$) and B4 has five independent elastic constants (C_{11} , C_{12} , C_{13} , C_{33} and C_{44} , $C_{11} = C_{22}$, $C_{44} = C_{55}$, $C_{66} = (C_{11} - C_{12})/2$, and $C_{13} = C_{23}$). The results for B3 are shown in Fig. 5 and the tendency with high pressure is not consistent for elastic constant: C_{11} and C_{12} increase with increasing pressure, which reflects that the compact arrangement of atoms lead to large repulsion among atoms. The relationships with pressure are linear: $\partial C_{11}/\partial P = 3.51$ (LDA), $\partial C_{11}/\partial P = 3.61$ (GGA), $\partial C_{12}/\partial P = 4.84$ (LDA), $\partial C_{12}/\partial P = 4.74$ (GGA). C_{44} shows a different tendency to C_{11} and C_{12} , which decreases with the increasing pressure and $\partial C_{44}/\partial P = -0.66$ for LDA and $\partial C_{44}/\partial P = -1.12$ for GGA.

The calculation results of crystal constants of B4 ZnO are shown in Fig. 6. Both a and c show a decreasing trend with increasing pressure, while the bulk modulus increases with increasing pressure (Fig. 7). The experimental results for crystal constants are a = 3.25 Å and c = 5.21 Å under atmospheric pressure, which lie



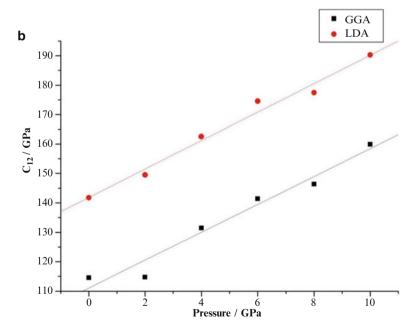


Fig. 5 Relationship between elastic constants and pressure for the B_3 structure: (a) C_{11} , (b) C_{12} , (c) C_{44}

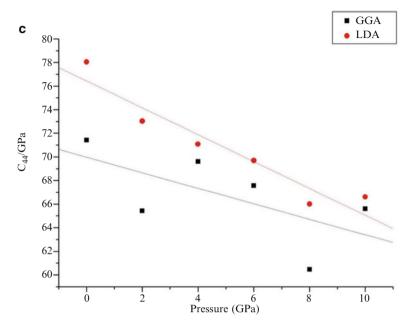


Fig. 5 (continued)

within the range of the GGA (a = 3.285 Å and c = 5.297 Å) and LDA (a = 3.191 Å and c = 5.158 Å) calculations. As the atoms of a ZnO crystal become much closer under higher pressure, the repulsion between atoms become much larger, which lead to an increase of the bulk modulus. The results obtained by LDA are larger than the ones by GGA.

B4 ZnO has five independent elastic constants and results are shown in Fig. 8. C_{11} , C_{12} , C_{13} and C_{33} increase with increasing pressure while only C_{44} is in the opposite trend. The straight lines shown in Fig. 8 were made according to the least square method. The pressure derivatives are as follows: $\partial C_{11}/\partial P = 3.35$ (LDA), $\partial C_{11}/\partial P = 1.93$ (GGA), $\partial C_{12}/\partial P = 5.16$ (LDA), $\partial C_{12}/\partial P = 2.41$ (GGA), $\partial C_{13}/\partial P = 4.63$ (LDA), $\partial C_{13}/\partial P = 1.75$ (GGA), $\partial C_{33}/\partial P = 2.76$ (LDA), $\partial C_{33}/\partial P = 1.69$ (GGA), $\partial C_{44}/\partial P = -1.06$ (LDA), $\partial C_{44}/\partial P = -0.81$ (GGA).

Table 1 shows the calculated and experimental results for the elastic constants from previous research, together with our results. Most experiments and calculations were carried out under atmospheric pressure; thus only the results with 0 environmental pressure are listed in the table. Compared with other research results, our results are consistent and the errors are small, which gives us confidence in the techniques employed.

The full anisotropic elastic response is not widely used in engineering applications. For simplicity, the material is generally treated as a homogeneous material. Thus only two constants are sufficient to describe the elastic properties without

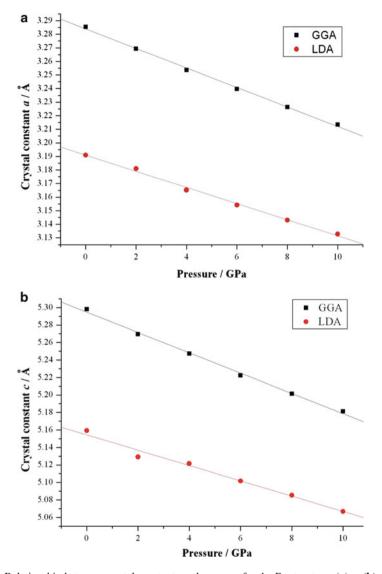


Fig. 6 Relationship between crystal constants and pressure for the B_3 structure: (a) a, (b) c

much error. For zinc blende ZnO, Young's modulus, E, Poisson's ratio ν , and the bulk modulus, B, the shear modulus, G, can be determined using the following expressions:

$$E = \frac{(C_{11} + 2C_{12})(C_{11} - C_{12})}{C_{11} + C_{12}},$$
(1)

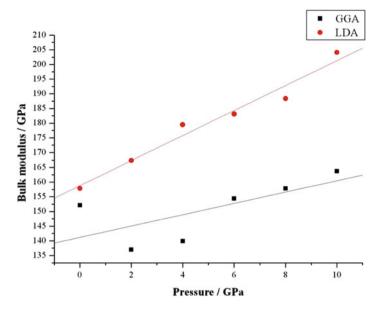


Fig. 7 Relationship between bulk modulus and pressure for the B₄ structure

$$\nu = \frac{C_{12}}{C_{11} + C_{12}},\tag{2}$$

$$B = \frac{C_{11} + 2C_{12}}{3},\tag{3}$$

and

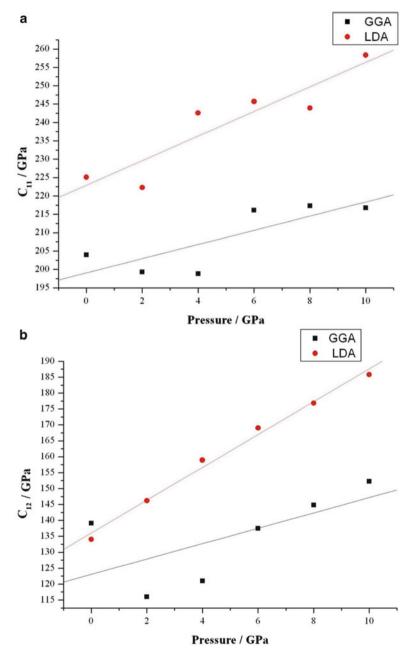
$$G = \frac{C_{11} - C_{12}}{2} = \frac{E}{2(1 + \nu)}.$$
 (4)

For B4 ZnO, in the isotropic approximation, the bulk modulus, B, shear modulus, G, Young's modulus, E, and Poisson's ratio, ν , can be evaluated using the relations [10]:

$$E = 3 \frac{(C_{11} + C_{12} - 2C_{13})[(C_{11} + C_{12})C_{33} - 2C_{13}^{2}]}{(C_{11} + C_{12} + 2C_{33} - 4C_{13})(C_{11} + C_{12})},$$
(5)

$$\nu = \frac{C_{13}}{C_{11} + C_{12}},\tag{6}$$

$$B = \frac{(C_{11} + C_{12})C_{33} - 2C_{13}^2}{C_{11} + C_{12} + 2C_{33} - 4C_{13}},$$
(7)



 $\textbf{Fig. 8} \ \ \text{Relationship between elastic constants and pressure for the B_4 structure: (a) C_{11}, (b) C_{12}, (c) C_{13}, (d) C_{33}, (e) C_{44}}$

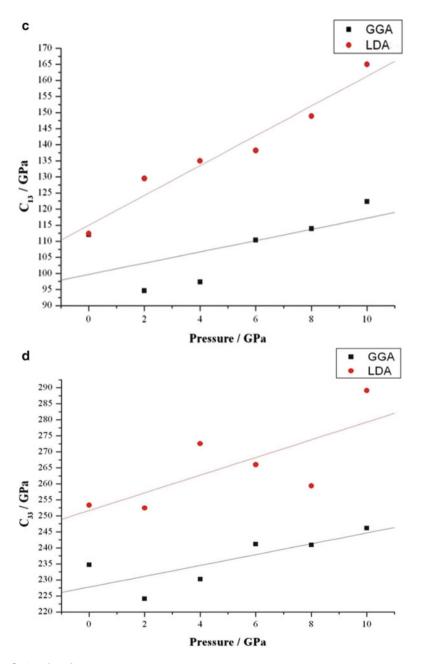


Fig. 8 (continued)

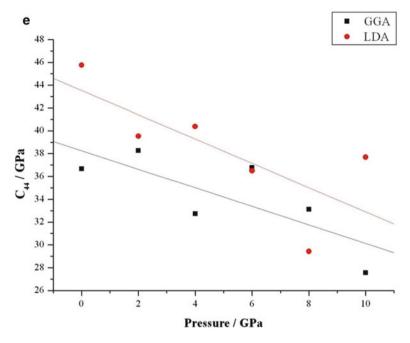


Fig. 8 (continued)

Table 1 Elastic properties of ZnO with both Zinc blende and Wurtzite structures obtained by experiments and calculations

Parameters (GPa)	Zinc blend		Wurtzite	
C ₁₁	193 [<mark>10</mark>]	184.7 (LDA)	209.7 [7], 206 [8],	223.8 (LDA)
		153.5 (GGA)	157 [9], 246 [10]	204.0 (GGA)
C_{12}	139 [<mark>10</mark>]	141.7 (LDA)	121.1 [7], 117 [8]	132.9 (LDA)
		114.5 (GGA)	89 [9], 127 [10]	139.1 (GGA)
C ₁₃			105.1 [7], 118 [8], 83 [9], 105 [10]	110.9 (LDA)
				112.0 (GGA)
C_{33}			210.9 [7], 211 [8], 208 [9], 246 [10]	45.8 (LDA)
				234.7 (GGA)
C ₄₄	96 [10]	78.0 (LDA)	42.47 [7], 44.3 [8], 38 [9], 56 [10]	45.7 (LDA)
		71.4 (GGA)		36.7 (GGA)
Bulk modulus	154.4 [12]	156.0 (LDA)	142.4 [11], 183 [12]	156.4 (LDA)
		127.5 (GGA)		152.1 (GGA)

and

$$G = \frac{3(C_{11} + C_{12} - 2C_{13})[(C_{11} + C_{12})C_{33} - 2C_{13}^{2}]}{2(C_{11} + C_{12} + 2C_{33} - 4C_{13})(C_{11} + C_{12} + C_{13})} = \frac{E}{2(1 + \nu)}.$$
 (8)

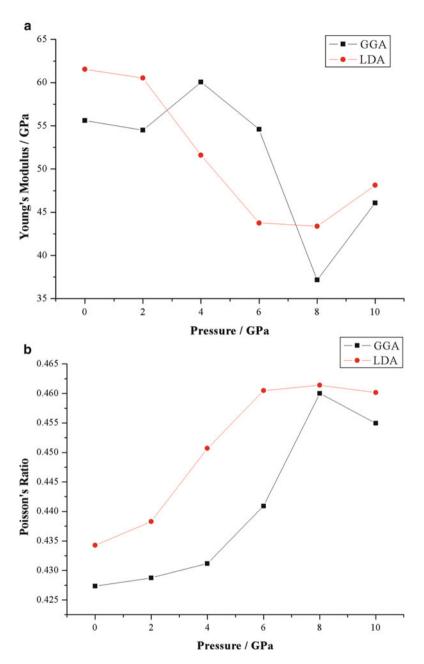


Fig. 9 Relationship between young's modulus, poisson's ratio and pressure for the B_3 structure: (a) Young's modulus, (b) Poisson's ratio

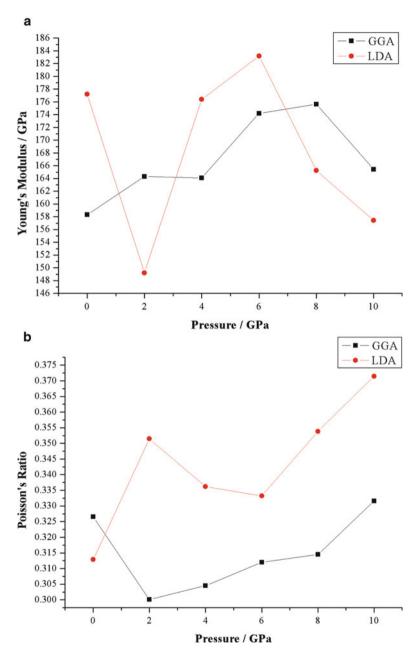


Fig. 10 Relationship between young's modulus, poisson's ratio and pressure for the B_4 structure: (a) Young's modulus, (b) Poisson's ratio

For B3 ZnO under atmospheric pressure, the Young's moduli are 61.7 GPa (LDA) and 55.7 GPa (GGA), while Poisson's ratio is 0.43 for both models. For B4 ZnO under the same conditions, Young's modulus is 180 GPa (LDA) and 158 GPa (GGA), and Poisson's ratio is 0.31 (LDA) and 0.33 (GGA). The relationships between Young's modulus, Poisson's ratio and pressure for B3 structures are shown in Fig. 9 while Fig. 10 shows the results for B4. From the figures, we find that the Young's moduli for the two structures do not simply increase with increasing pressure. The Young's modulus for B3 is lower at higher pressure, while the result for B4 was irregular. Poisson's ratios for the two structures become larger at higher pressure, which reflects the observation that the compressibility decreases with increasing environmental pressure. The shear modulus G, which is not an independent constant, can be directly deduced from Young's modulus and Poisson's ratio.

4 Conclusions

In this paper, calculations based on DFT were carried out to investigate the elastic properties and crystal structures of ZnO single crystals under high pressure. Both zinc blende and wurtzite structures were included in the calculation. CASTEP with both GGA and LDA was employed to investigate the behavior of longitudinal and shear modes for a ZnO single crystal under high pressure. The obtained results accord well with previous works. For zinc blende ZnO, results obtained by DFT show that the bulk modulus, C₁₁ and C₁₂ increase with increasing pressure, while the crystal lattice constant and C₄₄ show a different trend. The elastic constants obtained by LDA are larger than GGA, and the experimental lattice constant lies between the results of the two approximations. Further investigations on Young's moduli showed that E decreases with increasing pressure for B3 and no rules were found for B4. Under still higher pressure, Poisson's ratio was found to be larger. These results are helpful to widen the application of ZnO nanomaterials.

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